

UNR222x Series (UN222x Series)

Silicon NPN epitaxial planar type

For digital circuits

■ Features

- Costs can be reduced through downsizing of the equipment and reduction of the number of parts.
- Mini type package allowing easy automatic insertion through tape packing and magazine packing

■ Resistance by Part Number

		Marking Symbol (R ₁)		(R ₂)
• UNR2221	(UN2221)	9A	2.2 kΩ	2.2 kΩ
• UNR2222	(UN2222)	9B	4.7 kΩ	4.7 kΩ
• UNR2223	(UN2223)	9C	10 kΩ	10 kΩ
• UNR2224	(UN2224)	9D	2.2 kΩ	10 kΩ

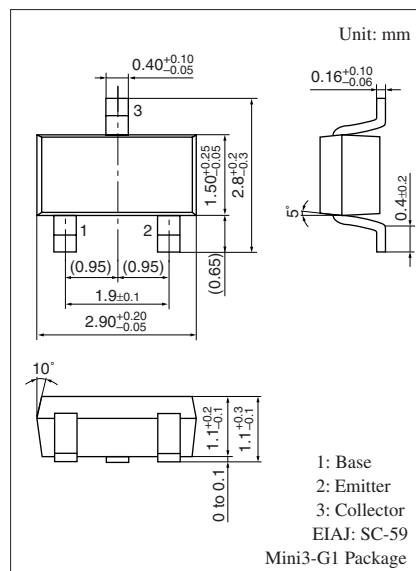
■ Absolute Maximum Ratings T_a = 25°C

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V _{CBO}	50	V
Collector-emitter voltage (Base open)	V _{CEO}	50	V
Collector current	I _C	500	mA
Total power dissipation	P _T	200	mW
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

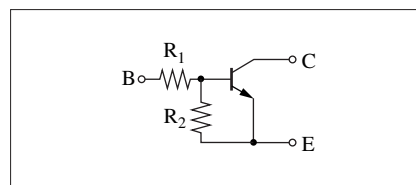
■ Electrical Characteristics T_a = 25°C ± 3°C

Parameter		Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)		V _{CBO}	I _C = 10 μA, I _E = 0	50			V
Collector-emitter voltage (Base open)		V _{CEO}	I _C = 2 mA, I _B = 0	50			V
Collector-base cutoff current (Emitter open)		I _{CBO}	V _{CB} = 50 V, I _E = 0			1	μA
Collector-emitter cutoff current (Base open)		I _{CEO}	V _{CE} = 50 V, I _B = 0			1	μA
Emitter-base cutoff current (Collector open)	UNR2221	I _{EBO}	V _{EB} = 6 V, I _C = 0			5	mA
	UNR2222					2	
	UNR2223/2224					1	
Forward current transfer ratio	UNR2221	h _{FE}	V _{CE} = 10 V, I _C = 100 mA	40			—
	UNR2222			50			
	UNR2223/2224			60			
Collector-emitter saturation voltage		V _{CE(sat)}	I _C = 10 mA, I _B = 5 mA			0.25	V
Output voltage high-level		V _{OH}	V _{CC} = 5 V, V _B = 0.5 V, R _L = 500 Ω	4.9			V
Output voltage low-level		V _{OL}	V _{CC} = 5 V, V _B = 3.5 V, R _L = 500 Ω			0.2	V

Note) The part numbers in the parenthesis show conventional part number.



Internal Connection

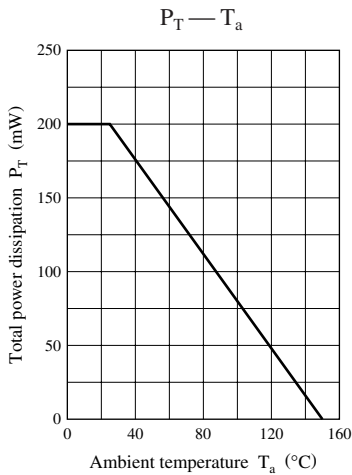


■ Electrical Characteristics (continued) $T_a = 25^{\circ}\text{C} \pm 3^{\circ}\text{C}$

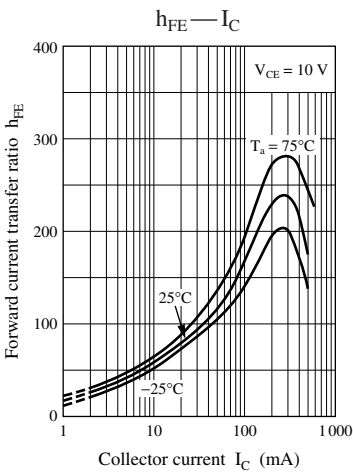
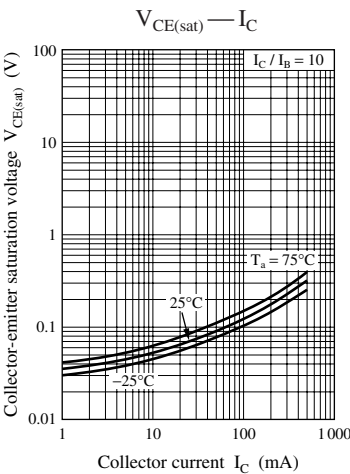
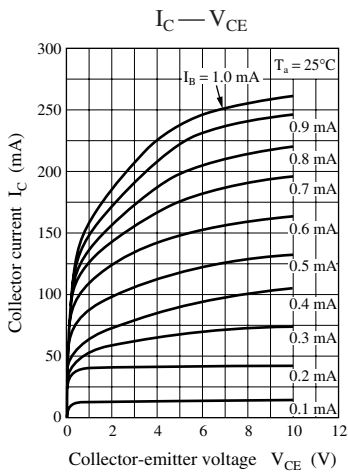
Parameter		Symbol	Conditions	Min	Typ	Max	Unit
Transition frequency		f_T	$V_{CB} = 10\text{ V}$, $I_E = -50\text{ mA}$, $f = 200\text{ MHz}$		200		MHz
Input resistance	UNR2221/2224	R_1		-30%	2.2	+30%	$\text{k}\Omega$
	UNR2222				4.7		
	UNR2223				10		
Resistance ratio		R_1/R_2		0.8	1.0	1.2	—
	UNR2224			0.17	0.22	0.27	

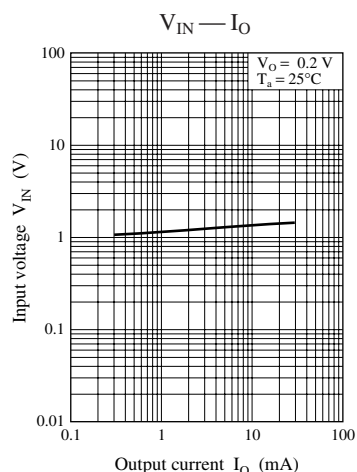
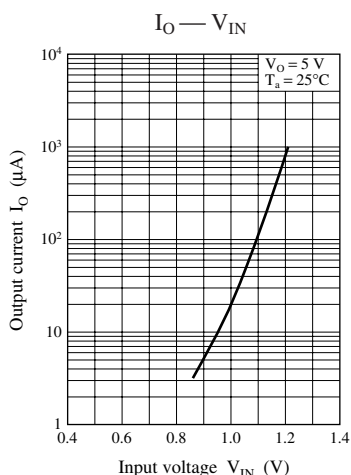
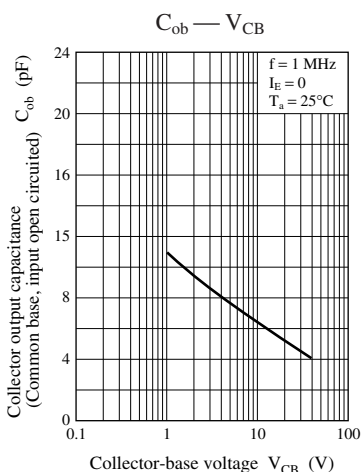
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

Common characteristics chart

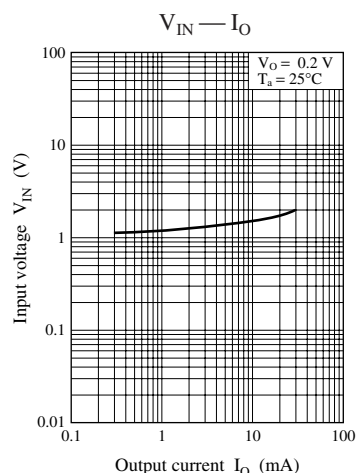
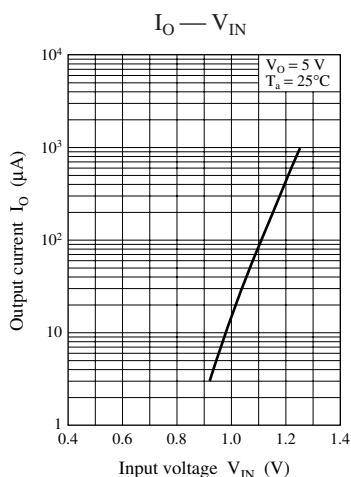
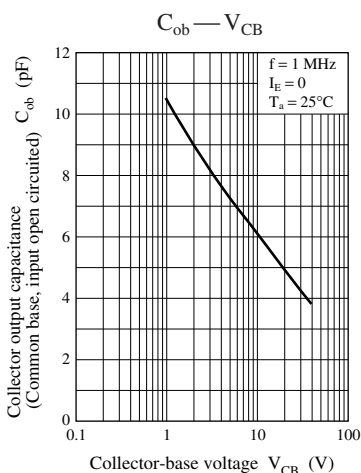
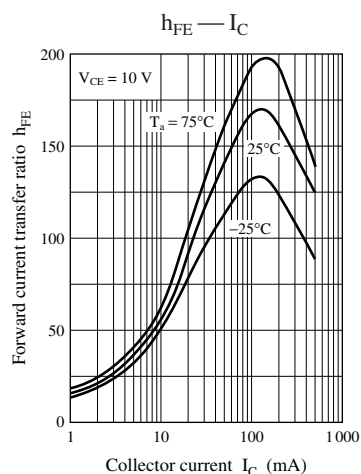
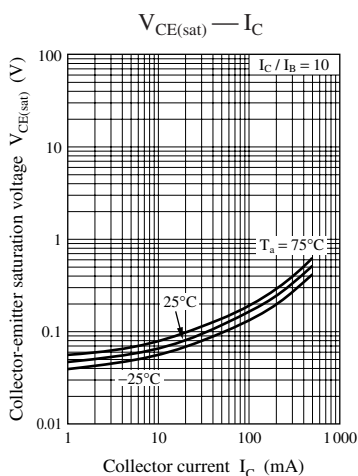
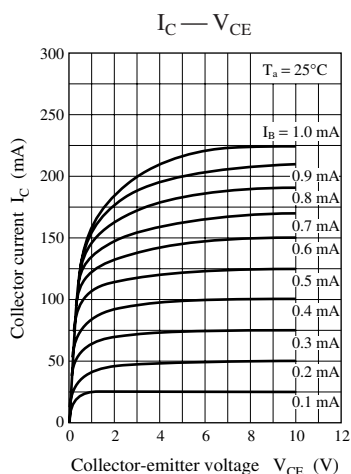


Characteristics charts of UNR2221

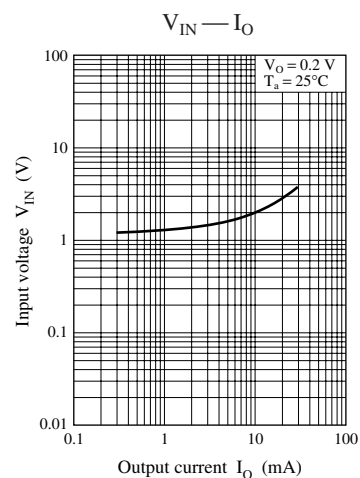
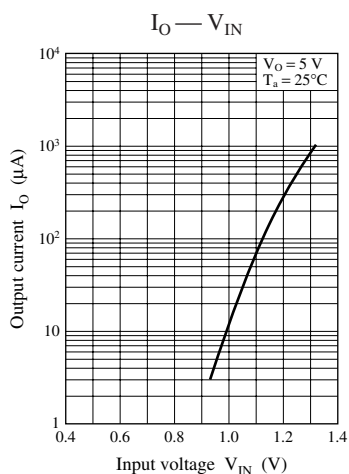
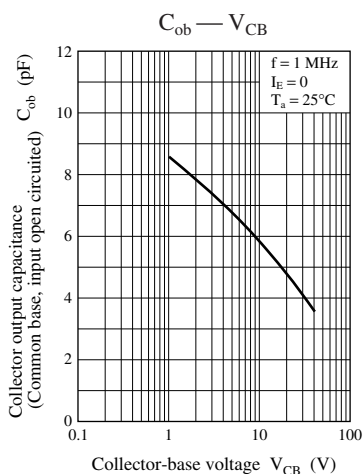
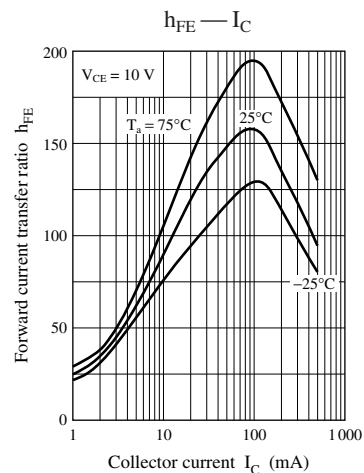
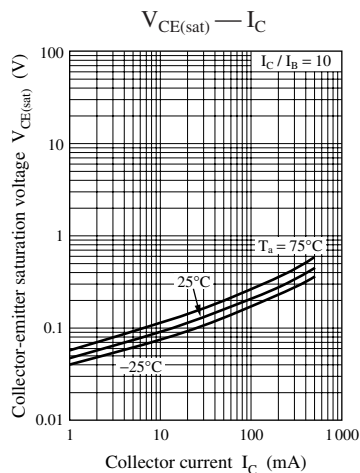
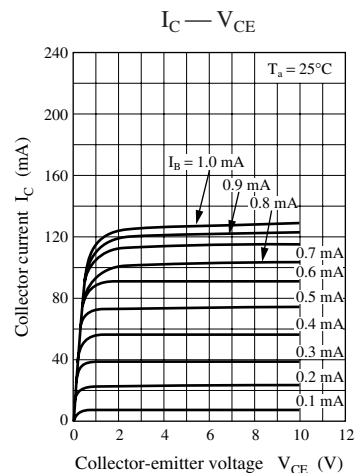




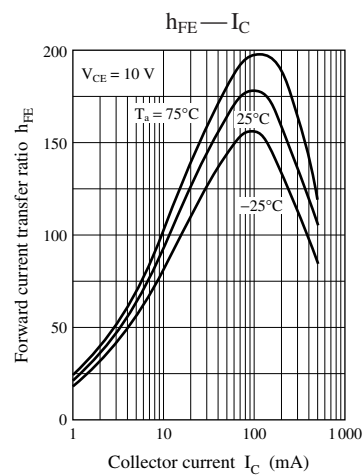
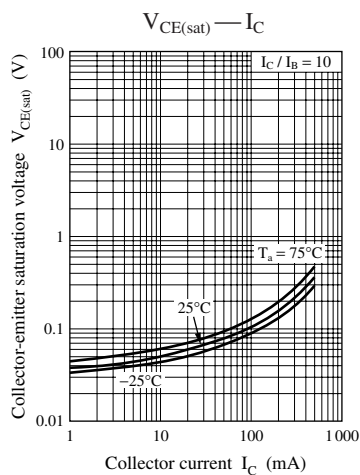
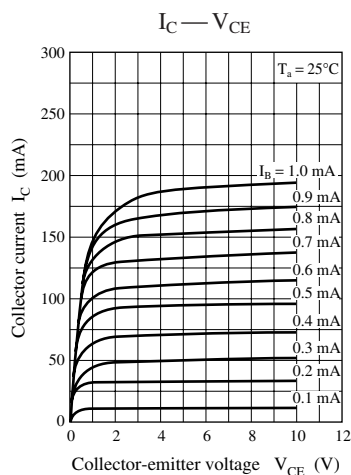
Characteristics charts of UNR2222

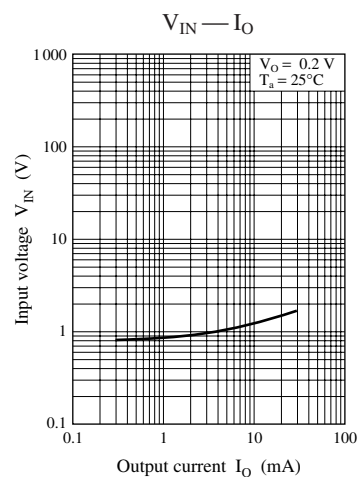
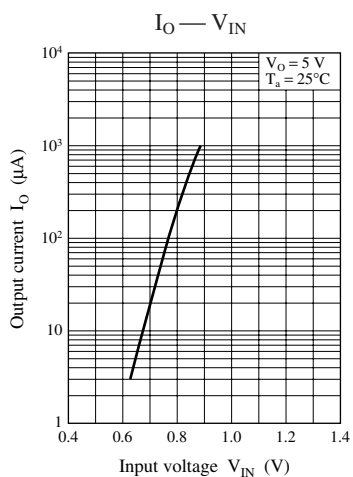
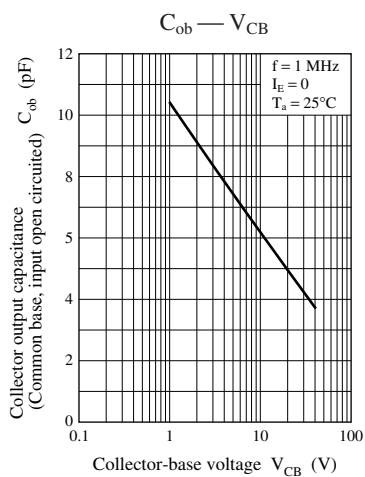


Characteristics charts of UNR2223



Characteristics charts of UNR2224





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